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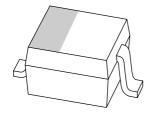
If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

# DISCRETE SEMICONDUCTORS

# DATA SHEET



# **BAS416**Low-leakage diode

Product data sheet Supersedes data of 2002 Nov 19 2004 Jan 26



# Low-leakage diode

**BAS416** 

### **FEATURES**

• Plastic SMD package

• Low leakage current: typ. 3 pA

• Switching time: typ. 0.8 μs

• Continuous reverse voltage: max. 75 V

• Repetitive peak reverse voltage: max. 85 V

• Repetitive peak forward current: max. 500 mA.

# **APPLICATIONS**

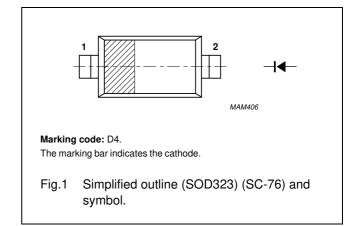
Low-leakage current applications in surface mounted circuits.

# **DESCRIPTION**

Epitaxial, medium-speed switching diode with a low leakage current encapsulated in a small SOD323 SMD plastic package.

### **PINNING**

PIN	DESCRIPTION
1	cathode
2	anode



### **ORDERING INFORMATION**

TYPE		PACKAGE				
NUMBER	NAME	DESCRIPTION VER				
BAS416	_	plastic surface mounted package; 2 leads	SOD323			

# **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>RRM</sub>	repetitive peak reverse voltage		_	85	V
$V_R$	continuous reverse voltage		_	75	V
I <sub>F</sub>	continuous forward current	see Fig.2	_	200	mA
I <sub>FRM</sub>	repetitive peak forward current		_	500	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; T <sub>j</sub> = 25 °C prior to surge; see Fig.4			
		t = 1 μs	_	4	Α
		t = 1 ms	_	1	Α
		t = 1 s	_	0.5	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; note 1	_	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C

# Note

1. Device mounted on an FR4 printed-circuit board.

# Low-leakage diode

**BAS416** 

# **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V <sub>F</sub>	forward voltage	see Fig.3			
		I <sub>F</sub> = 1 mA	_	0.9	V
		$I_F = 10 \text{ mA}$	_	1	V
		$I_F = 50 \text{ mA}$	_	1.1	V
		I <sub>F</sub> = 150 mA	_	1.25	V
I <sub>R</sub>	reverse current	see Fig.5			
		$V_R = 75 \text{ V}$	0.003	5	nA
		V <sub>R</sub> = 75 V; T <sub>j</sub> = 150 °C	3	80	nA
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 0; f = 1 MHz; see Fig.6	2	_	pF
t <sub>rr</sub>	reverse recovery time	when switched from $I_F$ = 10 mA to $I_R$ = 10 mA; $R_L$ = 100 $\Omega$ ; measured at $I_R$ = 1 mA; see Fig.7	0.8	3	μs

# THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	note 1	450	K/W

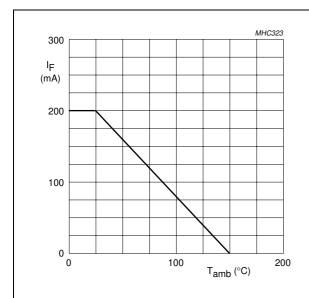
# Note

1. Refer to SOD323 (SC-76) standard mounting conditions.

# Low-leakage diode

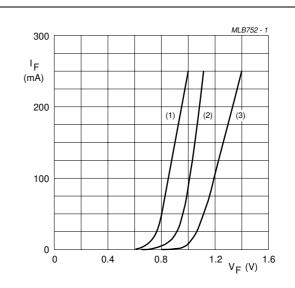
**BAS416** 

# **GRAPHICAL DATA**



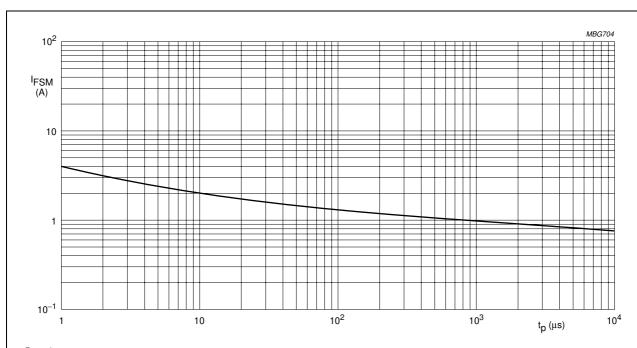
Device mounted on an FR4 printed-circuit board.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.



- (1)  $T_i = 150 \,^{\circ}\text{C}$ ; typical values.
- (2) T<sub>i</sub> = 25 °C; typical values.
- (3)  $T_i = 25 \,^{\circ}\text{C}$ ; maximum values.

Fig.3 Forward current as a function of forward voltage.



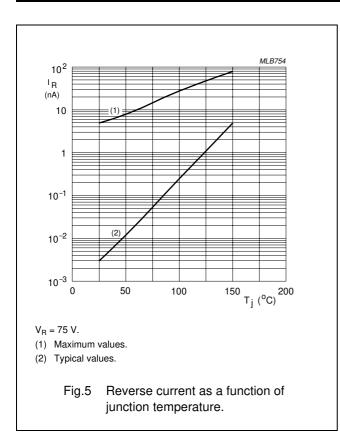
Based on square wave currents.

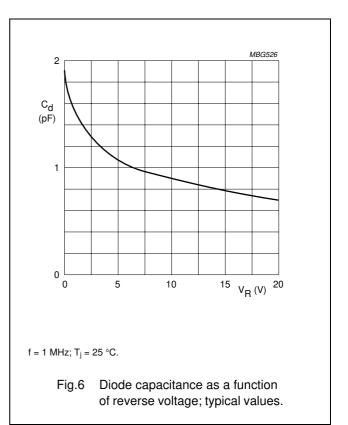
 $T_j$  = 25 °C prior to surge.

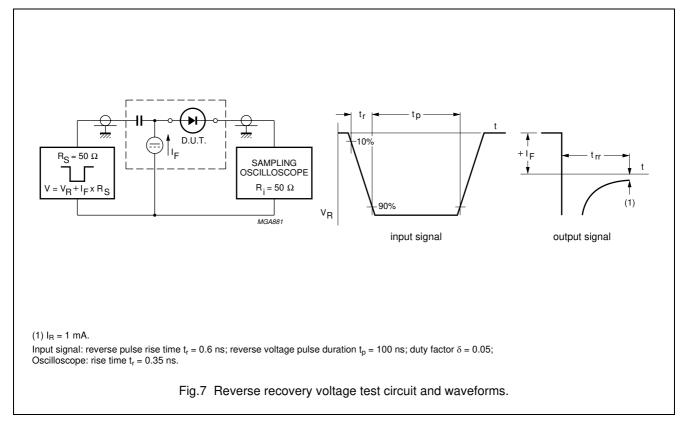
Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

# Low-leakage diode

**BAS416** 







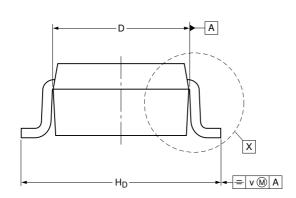
# Low-leakage diode

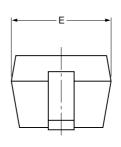
**BAS416** 

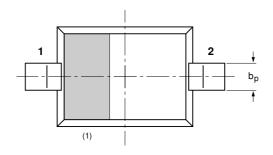
# **PACKAGE OUTLINE**

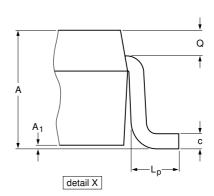
Plastic surface-mounted package; 2 leads

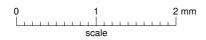
SOD323











# DIMENSIONS (mm are the original dimensions)

UNIT	A	A <sub>1</sub> max	bp	С	D	E	H <sub>D</sub>	Lp	Q	v
mm	1.1 0.8	0.05	0.40 0.25	0.25 0.10	1.8 1.6	1.35 1.15	2.7 2.3	0.45 0.15	0.25 0.15	0.2

### Note

1. The marking bar indicates the cathode

OUTLINE		REFERENCES				ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOD323			SC-76			<del>03-12-17</del> 06-03-16

# Low-leakage diode

**BAS416** 

### **DATA SHEET STATUS**

DOCUMENT STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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# **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

# **Contact information**

For additional information please visit: http://www.nxp.com

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